

DATASHEET

6 PIN DIP PHOTODARLINGTON PHOTOCOUPLER TIL113, 4NXX, H11BX Series



Features:

- 4NXX series: 4N29, 4N30, 4N31, 4N32, 4N33
- H11BX series: H11B1, H11B2, H11B3, H11B255
- High isolation voltage between input and output (Viso=5000 V rms)
- Creepage distance >7.62 mm
- Operating temperature up to +110°C
- · Compact small outline package
- •The product itself will remain within RoHS compliant version
- Compliance with EU REACH
- UL and cUL approved(No. E214129)
- VDE approved (No. 132249)
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved
- CQC approved

Description

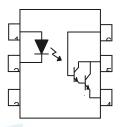
The TIL113, 4NXX and H11BX series of devices each consist of an infrared emitting diode optically coupled to a photo darlington detector.

They are packaged in a 6-pin DIP package and available in wide-lead spacing and SMD option.

Applications

- Low power logic circuits
- Telecommunications equipment
- Portable electronics
- Interfacing coupling systems of different potentials and impedances

Schematic



Pin Configuration

- 1. Anode
- 2. Cathode
- 3. No Connection
- 4. Emitter
- 5. Collector
- 6. Base



Absolute Maximum Ratings (Ta=25°C)

	Parameter	Symbol	Rating	Unit
	Forward current	I _F	60	mA
	Peak forward current (1us, pulse)	I _{FP}	1	Α
Input	Reverse voltage	I _F 60	V	
	Power dissipation	D	120	mW
	No derating required up to Ta = 100°C	P _D -	3.8	mW/°C
	Power dissipation	D	150	mW
	Derating factor (above Ta = 80°C)	P _C -	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	mW/°C
	Collector-Emitter voltage	V _{CEO}		V
Output	Collector-Base voltage	V_{CBO}	55	V
	Emitter-Collector voltage	V _{ECO}	7	V
	Emitter-Base voltage	V_{EBO}	7	V
Total power	dissipation	P _{TOT}	200	mW
Isolation voltage		V _{ISO}	5000	Vrms
Operating temperature		T _{OPR}	-55~+100	°C
Storage temperature		T _{STG}	-55~+125	°C
Soldering te	emperature *2	T _{SOL}	260	°C

Notes:

^{*1} AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1, 2 & 3 are shorted together, and pins 4, 5 & 6 are shorted together.

^{*2} For 10 seconds



Electro-Optical Characteristics (Ta=25°C unless specified otherwise)

Input

Parameter	Symbol	Min.	Тур.*	Max.	Unit	Condition
Forward Voltage	V _F	-	1.2	1.5	V	$I_F = 10 \text{mA}$ $I_F = 50 \text{mA for H11B3}$
Reverse Current	I_R	-	-	10	μΑ	$V_R = 6V$
Input capacitance	C_{in}	-	50	-	pF	V = 0, f = 1MHz

Output

Parameter	Symbol	Min.	Тур.*	Max.	Unit	Condition
Collector-Emitter dark current	I _{CEO}	-	-	100	nA	V _{CE} = 10V
Collector-Emitter breakdown voltage	BV_CEO	55	-	-	V	I _c =1mA
Emitter-Collector breakdown voltage	BV_CBO	55	-	-	V	I _C =0.1mA
Emitter-Collector breakdown voltage	BV _{ECO}	7	-		V	I _E =0.1mA

Transfer Characteristics (T_a=25°C unless specified otherwise)

Para	Parameter		Min	Тур.	Max.	Unit	Condition	
	4N32 4N33		500	-	-			
	4N29 4N30		100	-	-	_	$I_F = 10 \text{mA}, V_{CE} = 10 \text{V}$	
0 .	4N31	CTR	50	-	-	- %		
Current transfer	H11B1		500	-	-		I _F = 1mA ,V _{CE} = 5V	
ratio	H11B2		200	-	-			
	H11B3		100	-	-			
	H11B255		100	-	-	_	$I_F = 10 \text{mA}, V_{CE} = 5 \text{V}$	
	TIL113		300	-	-		$I_F = 10 \text{mA}, V_{CE} = 1 \text{V}$	



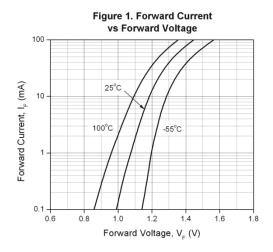
Transfer Characteristics (T_a=25°C unless specified otherwise)

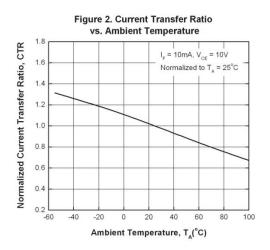
Parameter		Symbol	Min	Тур.	Max.	Unit	Condition
	4N29 4N30 4N32 4N33		-	-	1.0		$I_F = 8mA$, $I_c = 2mA$
Collector-e mitter saturation	4N31 TIL113	V _{CE(sat)}	-	-	1.2	V	$I_F = 8mA$, $I_c = 2mA$
voltage	H11B1 H11B2 H11B3	-	-	-	1.0	_	$I_F = 1mA$, $I_c = 1mA$
	H11B255	-	-	-	1.0	_	$I_F = 50 \text{mA}, I_c = 50 \text{mA}$
Isolation resi	Isolation resistance		10 ¹¹	-	-	Ω	V _{IO} = 500Vdc
Input-output Capacitance		C _{IO}	-	0.8	-	pF	V _{IO} = 0, f = 1MHz
	H11B1 H11B2 H11B3 H11B255		-	25	-		$V_{CC} = 10V, I_F = 10mA,$ $R_L = 100\Omega$
Turn-on time	4N29 4N30 4N31 4N32 4N33 TIL113	Ton	R	LI	5	μs	$V_{CC} = 10V, I_C = 50mA,$ $I_F = 200mA$
	H11B1 H11B2 H11B3 H11B255		-	18	-	-	$V_{CC} = 10V$, $I_F = 10mA$, $R_L = 100\Omega$
Turn-off time	4N32 4N33 TIL113	Toff	-	-	100	μs	$V_{CC} = 10V$,
	4N29 4N30 4N31	-	-	-	40	_	I _C = 50mA, I _F =200mA

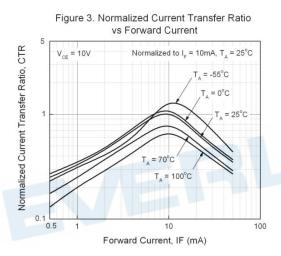
^{*} Typical values at T_a = 25°C

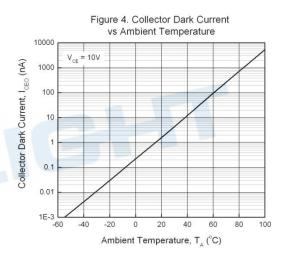


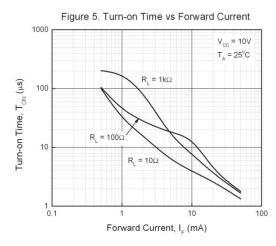
Typical Electro-Optical Characteristics Curves

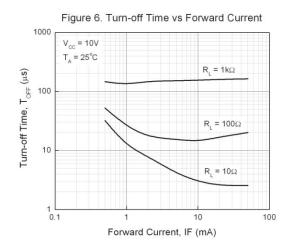














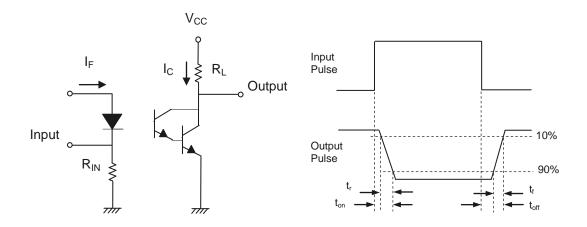


Figure 7. Switching Time Test Circuit & Waveforms





Order Information

Part Number

4NXXY(Z)-V or H11BXY(Z)-V or TIL113Y(Z)-V

Note

XX = Part No. for 4NXX series (29, 30, 31, 32 or 33)

X = Part No. for H11BX series (1, 2, 3 or 255)

Y = Lead form option (S, S1, M or none)

Z = Tape and reel option (TA, TB or none).

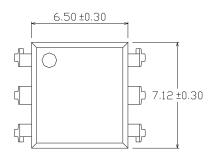
V = VDE safety (optional)

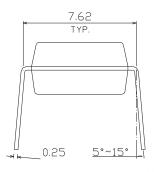
Option	Description	Packing quantity
None	Standard DIP-6	65 units per tube
M	Wide lead bend (0.4 inch spacing)	65 units per tube
S (TA)	Surface mount lead form + TA tape & reel option	1000 units per reel
S (TB)	Surface mount lead form + TB tape & reel option	1000 units per reel
S1 (TA)	Surface mount lead form (low profile) + TA tape & reel option	1000 units per reel
S1 (TB)	Surface mount lead form (low profile) + TB tape & reel option	1000 units per reel

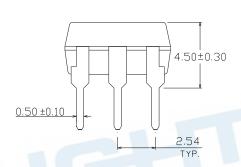


Package Dimension (Dimensions in mm)

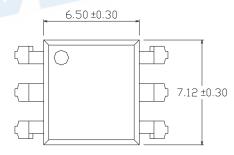
Standard DIP Type

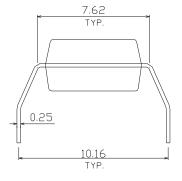


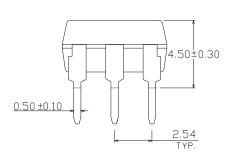




Option M Type

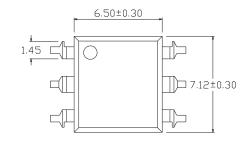


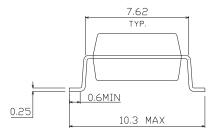


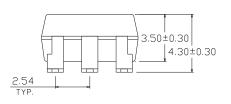




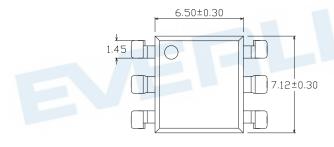
Option S Type

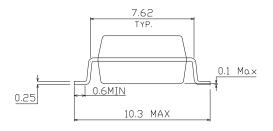


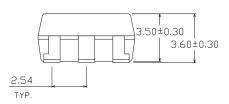




Option S1 Type

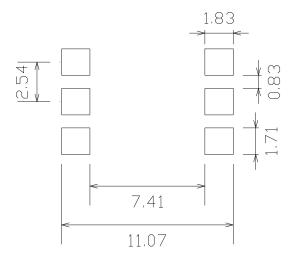








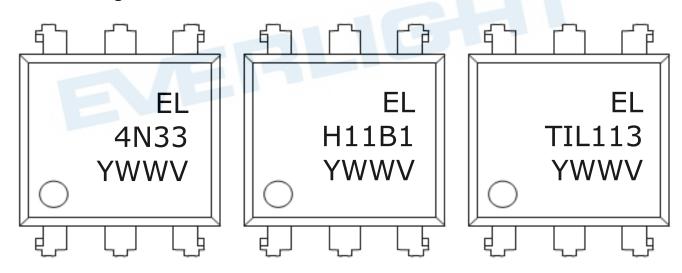
Recommended pad layout for surface mount leadform



Notes

Suggested pad dimension is just for reference only. Please modify the pad dimension based on individual need.

Device Marking



Notes

EL denotes Everlight

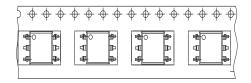
4N33 TIL113

H11B1 denotes Part Number
 Y denotes 1 digit Year code
 WW denotes 2 digit Week code
 V denotes VDE safety (optional)



Tape & Reel Packing Specifications

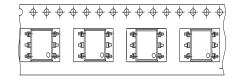
Option TA



Direction of feed from reel



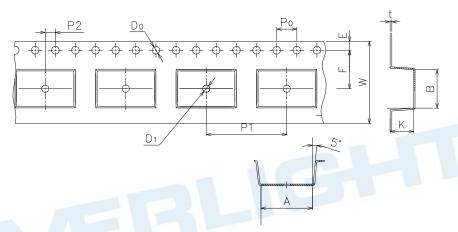
Option TB



Direction of feed from reel



Tape dimensions



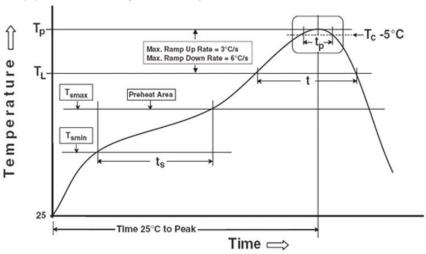
Dimension No.	Α	В	Do	D1	E	F
Dimension(mm)	10.8±0.1	7.55±0.1	1.5±0.1	1.5+0.1/-0	1.75±0.1	7.5±0.1
Dimension No.	Ро	P1	P2	t	W	К
Dimension(mm)	4.0±0.15	12±0.1	2.0±0.1	0.35±0.03	16.0±0.2	4.5±0.1



Precautions for Use

1. Soldering Condition

1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Note:

Preheat

Temperature min (T_{smin})

Temperature max (T_{smax})

Time $(T_{smin} \text{ to } T_{smax})$ (t_s)

Average ramp-up rate (T_{smax} to T_p)

Other

Liquidus Temperature (T₁)

Time above Liquidus Temperature (t L)

Peak Temperature (T_P)

Time within 5 °C of Actual Peak Temperature: T_P - 5°C

Ramp- Down Rate from Peak Temperature

Time 25°C to peak temperature

Reflow times

Reference: IPC/JEDEC J-STD-020D

150 °C

200°C

60-120 seconds

3 °C/second max

217 °C

60-100 sec

260°C

30 s

6°C /second max.

8 minutes max.

3 times



DISCLAIMER

- 1. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
- 2. The graphs shown in this datasheet are representing typical data only and do not show guaranteed values.
- 3. When using this product, please observe the absolute maximum ratings and the instructions for use outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
- 4. These specification sheets include materials protected under copyright of EVERLIGHT. Reproduction in any form is prohibited without the specific consent of EVERLIGHT.
- 5. This product is not intended to be used for military, aircraft, automotive, medical, life sustaining or life saving applications or any other application which can result in human injury or death. Please contact authorized Everlight sales agent for special application request.
- 6. Statements regarding the suitability of products for certain types of applications are based on Everlight's knowledge of typical requirements that are often placed on Everlight products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Everlight's terms and conditions of purchase, including but not limited to the warranty expressed therein.

单击下面可查看定价,库存,交付和生命周期等信息

>>Everlight(亿光)